TOIREX

XP131A1145SR

ETR1101_001

Power MOSFET

■ GENERAL DESCRIPTION

The XP131A1145SR is an N-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

The small SOP-8 package makes high density mounting possible.

■APPLICATIONS

- Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

■FEATURES

Low On-State Resistance : $Rds(on)=0.03 \Omega (Vgs=10V)$

: Rds(on)=0.045 Ω (Vgs=4.5V)

Ultra High-Speed Switching

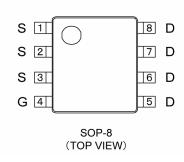
Driving Voltage : 4.5V

N-Channel Power MOSFET

DMOS Structure

Package : SOP-8

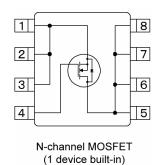
■PIN CONFIGURATION



■PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTION
1~3	S	Source
4	G	Gate
5~8	D	Drain

■EQUIVALENT CIRCUIT



■ ABSOLUTE MAXIMUM RATINGS

Ta = 25°C

PARAMETER	SYMBOL	RATINGS	UNITS
Drain-Source Voltage	Vdss	30	V
Gate-Source Voltage	Vgss	±20	V
Drain Current (DC)	Id	7	Α
Drain Current (Pulse)	ldp	30	Α
Reverse Drain Current	ldr	7	Α
Continuous Channel Power Dissipation *	Pd	2.5	W
Channel Temperature	Tch	150	°C
Storage Temperature Range	Tstg	-55~150	လ

^{*} When implemented on a glass epoxy PCB

■ELECTRICAL CHARACTERISTICS

DC Characteristics $Ta = 25^{\circ}C$

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	ldss	Vds=30V, Vgs=0V	-	-	10	μΑ
Gate-Source Leak Current	lgss	Vgs=±20V, Vds=0V	-	-	±1	μΑ
Gate-Source Cut-Off Voltage	Vgs(off)	Id=1mA, Vds=10V	1.0	-	2.5	٧
Drain-Source On-state Resistance *	Rds(on)	Id=4A, Vgs=10V	-	0.025	0.030	Ω
		Id=4A, Vgs=4.5V	-	0.035	0.045	Ω
Forward Transfer Admittance *	Yfs	Id=4A, Vds=10V	-	14	-	S
Body Drain Diode Forward Voltage	Vf	If=7A, Vgs=0V	-	0.85	1.1	V

^{*} Effective during pulse test.

Dynamic Characteristics

Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	Ciss	Vds=10V, Vgs=0V f=1MHz	-	620	-	pF
Output Capacitance	Coss		-	350	-	pF
Feedback Capacitance	Crss		-	120	-	pF

Switching Characteristics

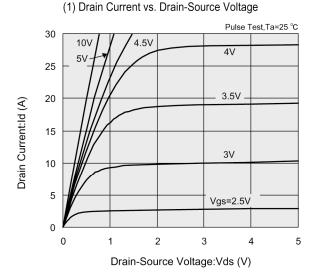
Ta = 25°C

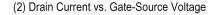
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-on Delay Time	td (on)	Vgs=5V, Id=4A Vdd=10V	ı	15	ı	ns
Rise Time	tr		-	20		ns
Turn-off Delay Time	td (off)		-	30	-	ns
Fall Time	tf		-	10	-	ns

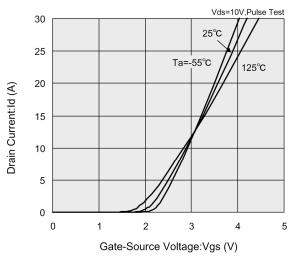
Thermal Characteristics

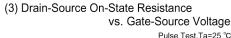
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (channel-ambience)	Rth (ch-a)	Implement on a glass epoxy resin PCB	-	50	-	°C/W

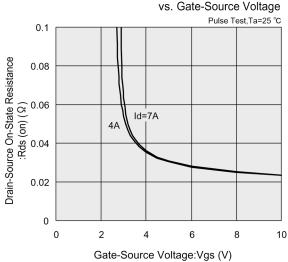
■TYPICAL PERFORMANCE CHARACTERISTICS



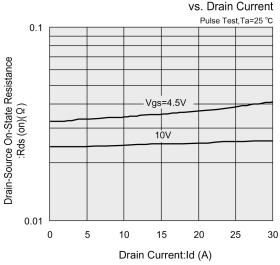




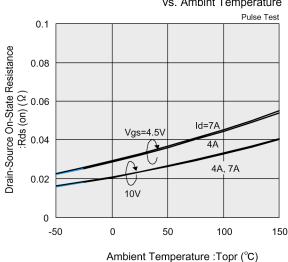




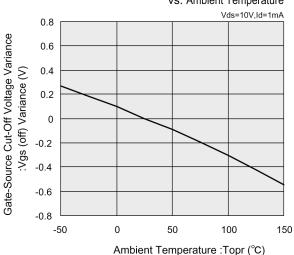
(4) Drain-Source On-State Resistance



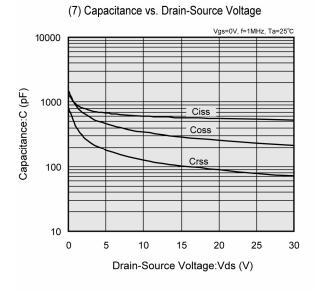
(5) Drain-Source On-State Resistance vs. Ambint Temperature

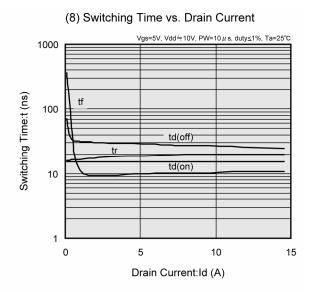


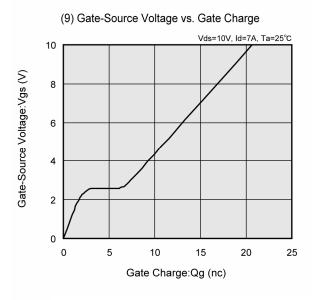
(6) Gate-Source Cut-Off Voltage Variance vs. Ambient Temperature

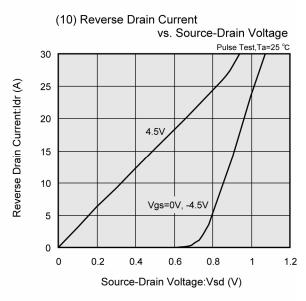


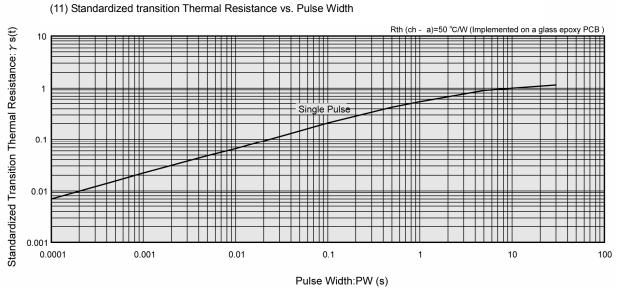
■TYPICAL RERFORMANCE CHARACTERISTICS (Continued)











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